Onsemi

MOSFET - Power, Single **N-Channel 40 V, 7.1 mΩ, 48 A** NVTFS008N04C

Features

- Small Footprint (3.3 x 3.3 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- NVTFWS008N04C Wettable Flanks Product
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parar	Symbol	Value	Unit		
Drain-to-Source Voltag	V _{DSS}	40	V		
Gate-to-Source Voltage	Э		V _{GS}	±20	V
Continuous Drain		$T_{C} = 25^{\circ}C$	I _D	48	А
Current R _{θJC} (Notes 1, 2, 3, 4)	Steady	$T_{C} = 100^{\circ}C$		27	
Power Dissipation	State	T _C = 25°C	PD	38	W
$R_{\theta JC}$ (Notes 1, 2, 3)		$T_{C} = 100^{\circ}C$		12	
Continuous Drain		T _A = 25°C	I _D	14	А
Current R _{θJA} (Notes 1, 3, 4)	Steady State	T _A = 100°C		10	
Power Dissipation		T _A = 25°C	PD	3.1	W
R _{θJA} (Notes 1, 3)		T _A = 100°C		1.5	
Pulsed Drain Current	$T_A = 25^{\circ}C, t_p = 10 \ \mu s$		I _{DM}	193	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			۱ _S	31	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 2.9 A)			E _{AS}	75	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

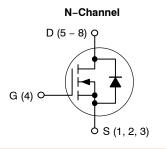
Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 3)	$R_{\theta JC}$	4	°C/W
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	48.6	

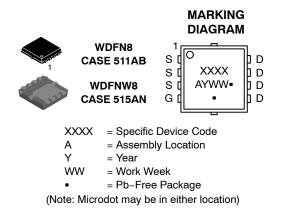
1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Psi (Ψ) is used as required per JESD51-12 for packages in which substantially less than 100% of the heat flows to single case surface.

 Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
Continuous DC current rating. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
40 V	8.5 mΩ @ 10 V	48 A





ORDERING INFORMATION

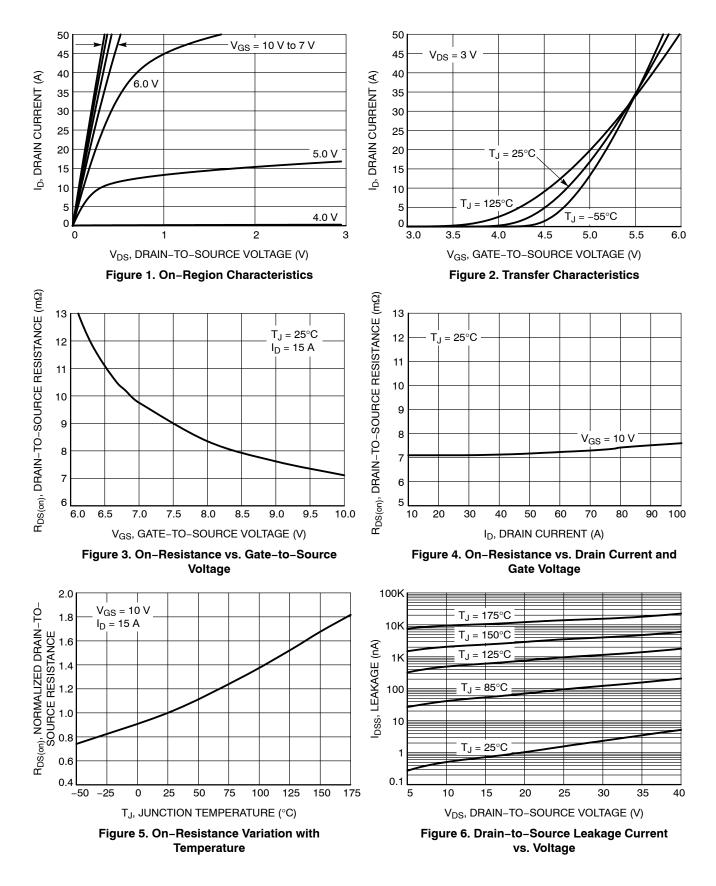
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

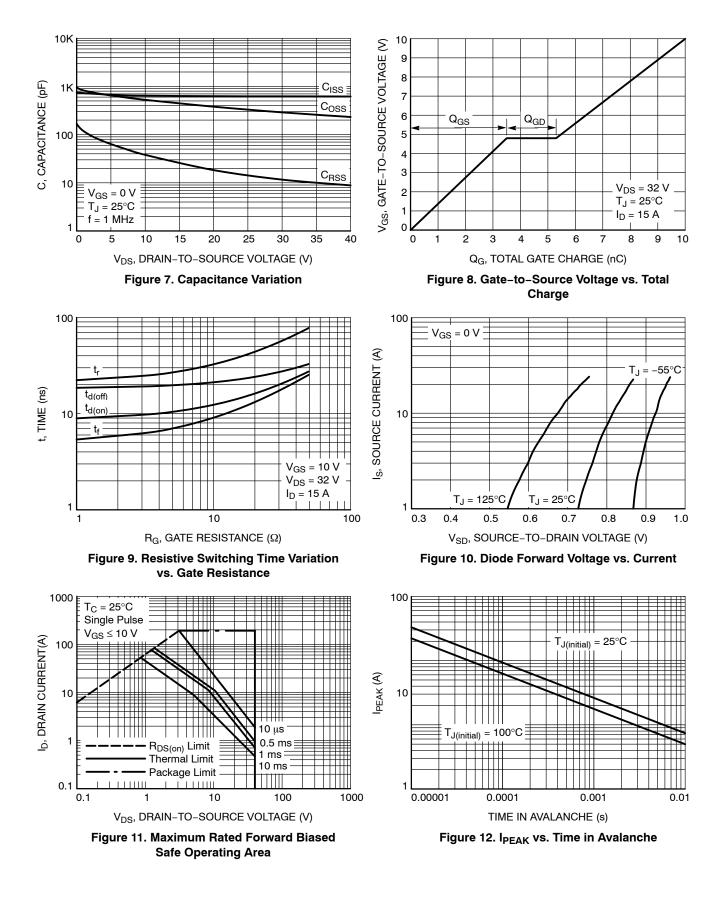
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	-	-			-		-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D =	= 250 μA	40			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			10	μΑ
		$V_{DS} = 40 V$	T _J = 125°C			250	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _G	_S = 20 V			100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= 30 μA	2.5		3.5	V
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _[_D = 15 A		7.1	8.5	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _E	_D = 15 A		29		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{iss}				625		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, f = V _{DS} = 25	1.0 MHz, 5 V		335		
Reverse Transfer Capacitance	C _{rss}				15		
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 10 V, V _{DS} = 32 V, I _D = 15 A			2.2		nC
Gate-to-Source Charge	Q _{GS}				3.5		1
Gate-to-Drain Charge	Q _{GD}				1.8		1
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 32 V, I_{D} = 15 A			10		nC
SWITCHING CHARACTERISTICS (No	te 6)						
Turn-On Delay Time	t _{d(on)}				9.5		ns
Rise Time	t _r	V _{GS} = 10 V, V _D	s = 32 V,		24		1
Turn-Off Delay Time	t _{d(off)}	I _D = 15			19		1
Fall Time	t _f	1			6		1
DRAIN-SOURCE DIODE CHARACTER	RISTICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.84	1.2	V
		I _S = 15 A	T _J = 125°C		0.71		1
Reverse Recovery Time	t _{RR}				24		ns
Charge Time	t _a	V _{GS} = 0 V, dl _S /dt	= 100 A/μs,		11		1
Discharge Time	t _b	I _S = 15	Α		12		1
Reverse Recovery Charge	Q _{RR}	1			11		nC

5. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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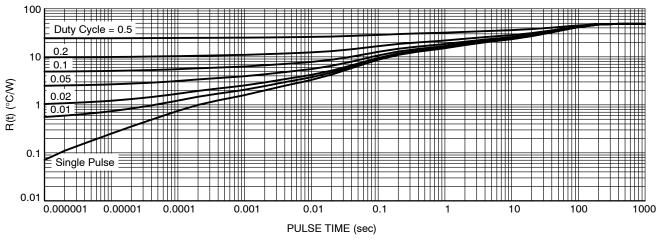


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVTFS008N04CTAG	08NC	WDFN8 (Pb–Free)	1500 / Tape & Reel
NVTFWS008N04CTAG	08NW	WDFNW8 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

WDFNW8 3.3x3.3, 0.65P (Full-Cut μ8FL WF) CASE 515AN

ISSUE O

NDTES

1. DIMENSIONING AND TOLERANCING PERASME Y14.5M, 2009.

MIN.

0.70

0.00

0.23

0.15

3.05

2.95

1.98

3.05

2.95

1.47

2. CONTROLLING DIMENSION MILLIMETERS

DIM

Α

A1

ю с

D

D1

D2

Е

E1

E2

3. DIMENSION DI AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

MILLIMETERS

NDM.

0.75

0.30

0.20

3.30

3.05

2.11

3.30

3.05

1.60

MAX.

0.80

0.05

0.40

0.25

3.55

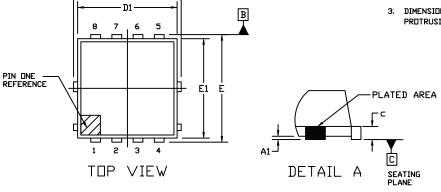
3.15

2.24

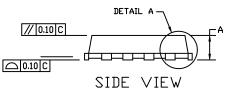
3.55

3.15

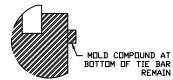
1.73



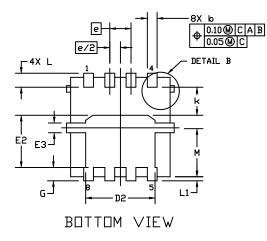
► A

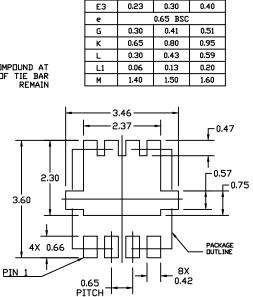


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DETAIL B





* For additional information on our Pb-Free strategy and soldering details, please download the IIN Semiconductor Soldering and Mounting Techniques Reference Manual, SULDERRM/D.

RECOMMENDED

MOUNTING FOOTPRINT

DATE 23 APR 2012





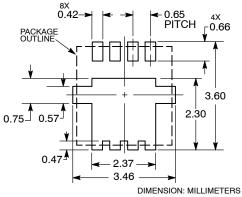
Pb-Free indicator, "G" or microdot " .", may or may not be present.

NOTES: LES: DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS. 1.

2. 3.

	м	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α	0.70	0.75	0.80	0.028	0.030	0.031		
A1	0.00		0.05	0.000		0.002		
b	0.23	0.30	0.40	0.009	0.012	0.016		
с	0.15	0.20	0.25	0.006	0.008	0.010		
D		3.30 BSC		0.130 BSC				
D1	2.95	3.05	3.15	0.116	0.120	0.124		
D2	1.98	2.11	2.24	0.078	0.083	0.088		
E	3.30 BSC			0.130 BSC				
E1	2.95	3.05	3.15	0.116	0.120	0.124		
E2	1.47	1.60	1.73	0.058	0.063	0.068		
E3	0.23	0.30	0.40	0.009	0.012	0.016		
е	0.65 BSC			0.026 BSC				
G	0.30	0.41	0.51	0.012	0.016	0.020		
к	0.65	0.80	0.95	0.026	0.032	0.037		
L	0.30	0.43	0.56	0.012	0.017	0.022		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
м	1.40	1.50	1.60	0.055	0.059	0.063		
θ	0 °		12 °	0 °		12 °		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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